

SBT2222A

NPN Silicon Transistor

Descriptions

- General purpose application
- Switching application

Features

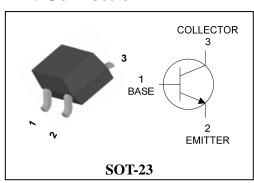
- Low Leakage current
- Low collector saturation voltage enabling low voltage operation
- Complementary pair with SBT2907A

Ordering Information

Type NO.	Marking	Package Code
SBT2222A	<u>1P</u> □ ① ②	SOT-23

①Device Code ②Year & Week Code

PIN Connection



Absolute maximum ratings

Ta=25°C

Characteristic	Symbol	Ratings	Unit
Collector-Base voltage	V_{CBO}	75	V
Collector-Emitter voltage	$V_{\sf CEO}$	40	V
Emitter-Base voltage	V_{EBO}	5	V
Collector ourrent	I _C	0.6	A(DC)
Collector current	I _{CP} *	1.2	A(Pulse)
Collector dissipation	Pc**	350	mW
Junction temperature	Tj	150	°C
Storage temperature range	T_{stg}	-55~150	°C

^{* :} Single pulse, tp= 300 μ s

Thermal Characteristics

Characteristic	Symbol	Ratings	Unit
Thermal resistance Junction-Ambient	R _{th(J-A)} **	357	°C/W
Thermal resistance Junction-Case	R _{th(J-C)} **	200	°C/W

^{** :} Package mounted on 99.5% alumina 10×8×0.6mm

KSD-T5C052-004 1

^{** :} Package mounted on 99.5% alumina 10×8×0.6mm

SBT2222A

Electrical Characteristics

Ta=25°C

Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Collector-Base breakdown voltage	BV _{CBO}	$I_C = 10 \mu A, I_E = 0$	75	-	-	V
Collector-Emitter breakdown voltage	Ilector-Emitter breakdown voltage BV_{CEO} $I_C=1mA$, $I_B=0$		40	-	-	V
Emitter-Base breakdown voltage	akdown voltage BV_{EBO} $I_E=10\mu A, I_C=0$		5	-	-	V
Collector cut-off current	I _{CBO}	V _{CB} =75V, I _E =0	-	-	20	nA
Collector cut-off current	I _{CEX}	V _{CE} =30V, V _{EB} =0.5V	-	-	50	nA
DC current gain	h _{FE}	V _{CE} =10V, I _C =10mA	100	-	-	-
Collector-Emitter saturation voltage	V _{CE(sat)}	I _C =150mA, I _B =15mA	-	-	0.4	V
Transition frequency	f _T	V _{CE} =20V, I _C =20mA, f=100MHz	250	-	-	MHz
Collector output capacitance	C _{ob}	$V_{CB}=10V$, $I_{E}=0$, $f=1MHz$	-	-	8	pF
Delay time	t _d	$V_{CC}=30V_{dc}$, $V_{BE(off)}=0.5V_{dc}$,	-	-	10	ns
Rise time	t _r	$I_{C} = 150 \text{mA}_{dc}, I_{B1} = 15 \text{mA}_{dc}$	-	-	25	ns
Storage time	t _s	V _{CC} =30V _{dc} , I _C =150mA _{dc} ,	-	-	225	ns
Fall Time	t _f	$I_{B1} = I_{B2} = 15 \text{mA}_{dc}$	-	-	60	ns

KSD-T5C052-004

2

Electrical Characteristic Curves

Fig. 1 P_C - T_a

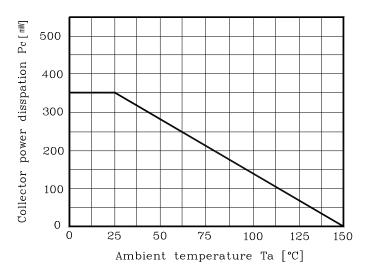


Fig. 2 h_{FE} - I_{C}

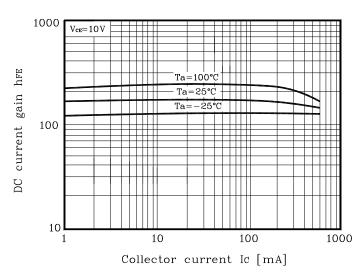


Fig. 3 I_C - $V_{CE(SAT)}$

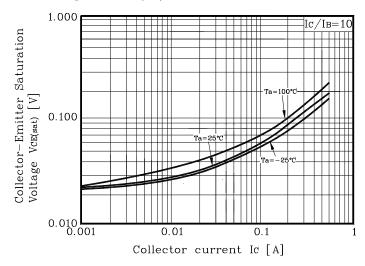


Fig. 4 $I_C - V_{BE(SAT)}$

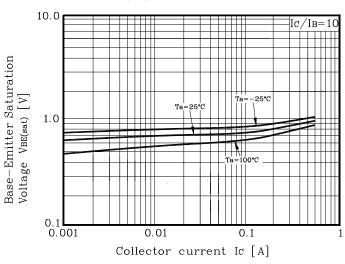
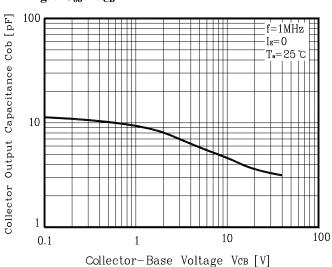
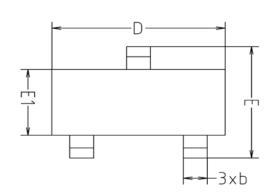
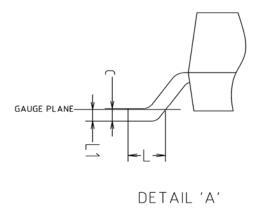


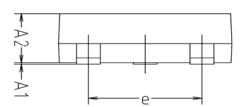
Fig. 5 C_{ob} - V_{CB}



Outline Dimension (Unit: mm)



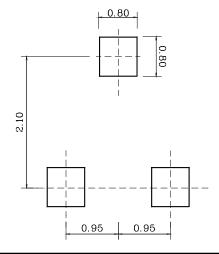






SYMBOL	MILLIMETERS			NOTE
STILLOCE	MINIMUM	NOMINAL	MAXIMUM	14012
A1	0.00	-	0.10	
A2	0.82	-	1.02	
Ь	0.39	0.42	0.45	
С	0.09	0.12	0.15	
D	2.80	2.90	3.00	
Ε	2.20	2.40	2.60	
E1	1.20	1.30	1.40	
е	1.90BSC			
L	0.20	-	-	
L1		0.12BSC		

****Recommend PCB solder land (Unit: mm)**



KSD-T5C052-004

4

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KSD-T5C052-004 5